

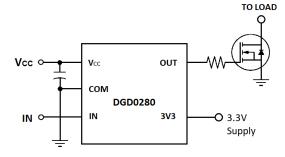
Description

The DGD0280 high-speed, low-side MOSFET and IGBT driver is capable of driving 1.9A of peak current. The DGD280 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with MCUs. Internal undervoltage lockout (UVLO) protects the MOSFET with loss of supply by turning off the output when VCC falls below operating range. Fast and well matched propagation delays allow high-speed operation, enabling a smaller, more compact power-switching design using smaller associated components.

The DGD0280 has an integrated LDO that outputs 3.3V at ±1% tolerance with the ability to supply 15mA. The DGD0280 provides a non-inverted output. The DGD0280 comes in a space-saving TSOT25 package and operates over an extended -40°C to +125°C temperature range.

Applications

- **DC-DC Converters**
- Line Drivers
- Motor Controls
- Switch Mode Power Supplies



Typical Configuration

Ordering Information (Note 4)

Part number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DGD0280WT-7	D0280	7	8	3000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



D0280 = Product Type Marking Code YY = Year (ex: 19 = 2019) WW or WW - = Week (01 - 53)

Features

- Integrated LDO (3.3V, 15mA Output)
- 3.3V LDO at 1% Accuracy at 25°C
- Wide Supply Voltage Operating Range: 4.5V to 18V
- 2.5A Source / 2.8A Sink Output Current Capability
- Undervoltage Lockout for Vcc Supply
- Fast Propagation Delay (35ns Typ)
- Fast Rise and Fall Times (20ns Typ)
- Logic Input (IN) 3.3V Capability
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

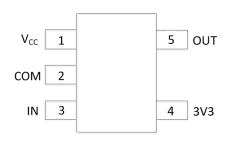
- Case: TSOT25
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish-Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.016 grams (Approximate)



TSOT25



Pin Diagrams

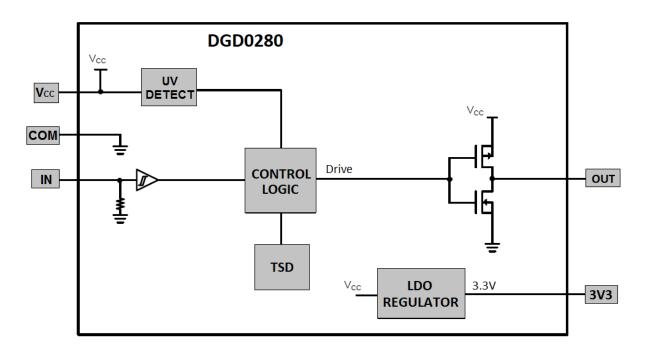




Pin Descriptions

Pin Number	Pin Name	Function
1	Vcc	Supply Input
2	COM	Supply Return
3	IN	Logic Input, In Phase with OUT
4	3V3	LDO Regulator 3.3V Ouput
5	OUT	Gate Drive Output

Functional Block Diagram





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Low-Side Fixed Supply Voltage	Vcc	-0.3 to +22	V
Output Voltage (OUT)	Vout	-0.3 to V _{CC} +0.3	V
Logic Input Voltage (IN)	V _{IN}	-5 to V _{CC} +0.3	V

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	PD	0.89	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	117	°C/W
Thermal Resistance, Junction to Case (Note 5)	Rejc	12.5	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	TL	+300	°C
Storage Temperature Range	T _{STG}	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board with minimum recommended pad layout.

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	2000	V	2
Electrostatic Discharge – Charged Device Model	ESD CDM	1000	V	IV

Note: 6. Refer to JEDEC specification JESD22-A114 and JESD22-C101.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _{CC}	4.5	18	V
Output Voltage (OUT)	Vout	0	Vcc	V
Logic Input Voltage (IN)	V _{IN}	0	5	V
Ambient Temperature	T _A	-40	+125	°C



DC Electrical Characteristics (V_{CC} = 12V, @T_A = +25°C, unless otherwise specified.) (Note 7)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Logic "1" Input Voltage	VIH	2.0	_	_	V	_
Logic "0" Input Voltage	VIL	—	_	0.8	V	—
Input Hysteresis	V _{IN_HYS}	_	0.5	_	V	
Logic "1" Input Bias Current	I _{IN+}	—	7.5	20	μA	V _{IN} = 3V
Logic "0" Input Bias Current	I _{IN-}	_	—	1	μA	$V_{IN} = 0V$
Quiescent V _{CC} Supply Current	Iccq	—	—	250	μA	Inputs Open
		_	1.5	—	mA	fs = 100kHz C _L = 1000pF
Operating V _{CC} Supply Current	Icco	—	12.5	—	mA	fs = 1MHz C _L = 1000pF
V _{CC} Supply Undervoltage Positive Going Threshold	V _{CCUV+}	4.5	4.75	5.0	V	—
V _{CC} Supply Undervoltage Negative Going Threshold	V _{CCUV-}	4.2	4.5	4.8	V	
Output High Short-Circuit Pulsed Current	I _{O+}	—	2.5	—	Α	$V_0 = 0V$, PW $\leq 10\mu s$
Output Low Short-Circuit Pulsed Current	I _{O-}	—	2.8	—	Α	V _O = 15V, PW ≤ 10µs
LDO Output Voltage	V _{LDO}	3.267	3.3	3.333	V	I _{OUT} = 10mA
LDO Line Regulation	VLDO_LINE		21	38	mV	V _{CC} = 5V to 18V, I _{OUT} = 10mA
LDO Load Regulation	V _{LDO_LOAD}	_	—	10	mV	V_{CC} = 12V, I _{OUT} = 0.1mA to 10mA
Maximum LDO Current	ILDO MAX		15	_	mA	RL = 220Ω
LDO Current Limit	ILDO LIM	20	68	_	mA	RL = 0Ω
Thermal Shutdown Turn On	TSDON	_	150	—	°C	—
Thermal Shutdown Turn Off	TSD _{OFF}	—	125	_	°C	—

Note: 7. The V_{IN} and I_{IN} parameters are applicable to the logic input pin: IN. The V_0 and I_0 parameters are applicable to the output pin: OUT.

AC Electrical Characteristics (V_{CC} = 12V, @T_A = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-on Rise Time	tr	—	20	35	ns	C _L = 1000pF
Turn-off Fall Time	t _f	—	15	35	ns	C _L = 1000pF
Turn-on Propagation Delay	t _{ON}	20	35	50	ns	—
Turn-off Propagation Delay	t _{OFF}	15	30	50	ns	—



DGD0280

Timing Waveforms

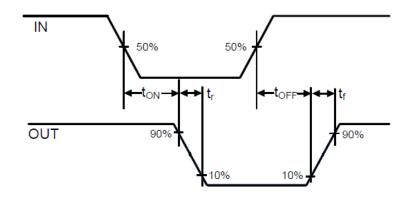


Figure 1. Switching Time Waveform Definitions

Typical Performance Characteristics (V_{CC} = 12V, @T_A = +25°C, unless otherwise specified.)

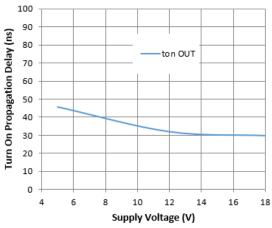


Figure 2. Turn-on Propagation Delay vs. Supply Voltage

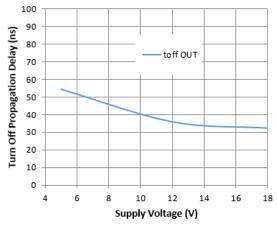
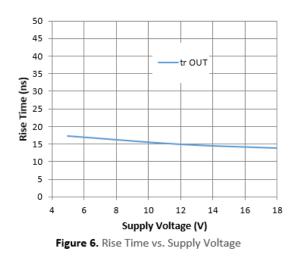


Figure 4. Turn-off Propagation Delay vs. Supply Voltage



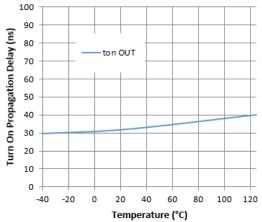


Figure 3. Turn-on Propagation Delay vs. Temperature

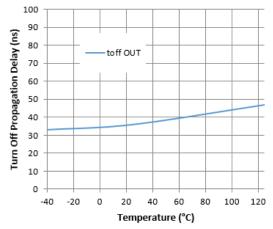
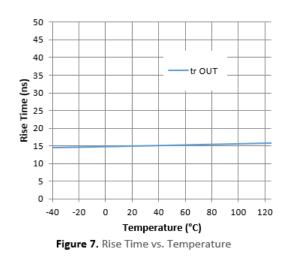
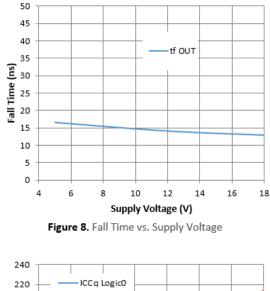


Figure 5. Turn-off Propagation Delay vs. Temperature





Typical Performance Characteristics (continued)



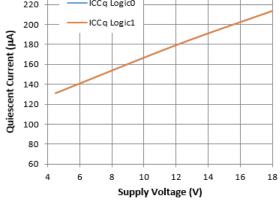


Figure 10. Quiescent Current vs. Supply Voltage

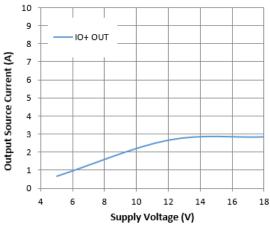
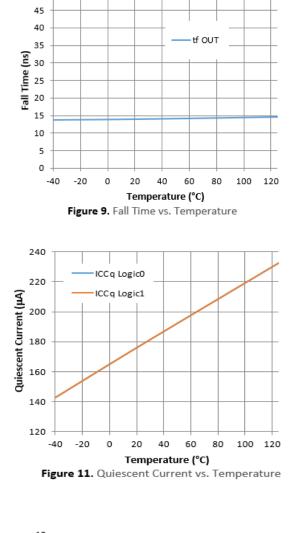


Figure 12. Output Source Current vs. Supply Voltage



50

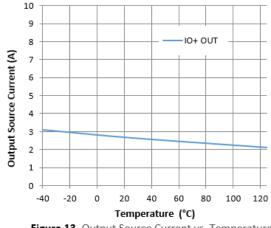


Figure 13. Output Source Current vs. Temperature



Typical Performance Characteristics (cont.)

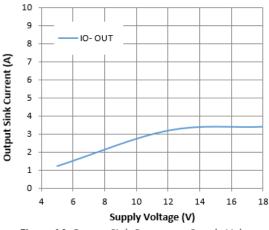


Figure 14. Output Sink Current vs. Supply Voltage

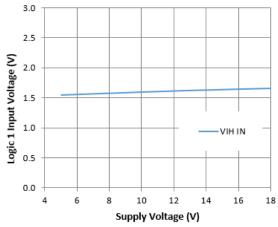


Figure 16. Logic 1 Input Voltage vs. Supply Voltage

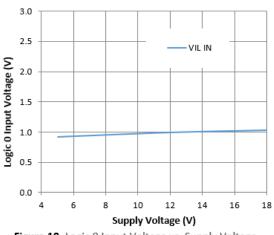
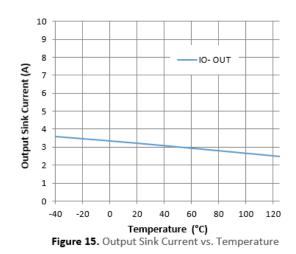
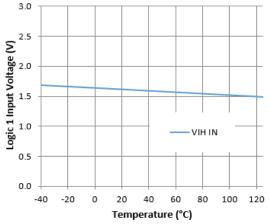
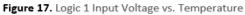
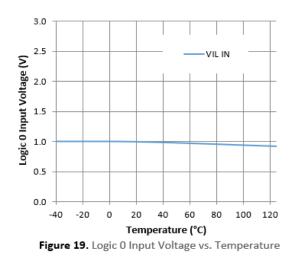


Figure 18. Logic 0 Input Voltage vs. Supply Voltage





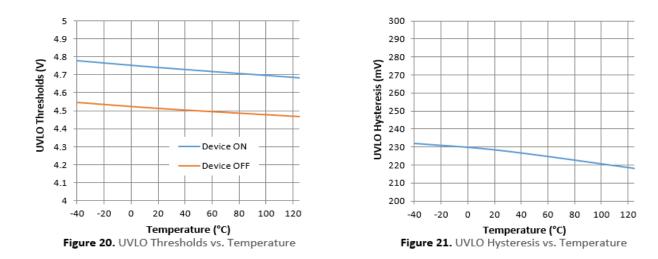




DGD0280 Document number: DS41282 Rev. 2 - 2



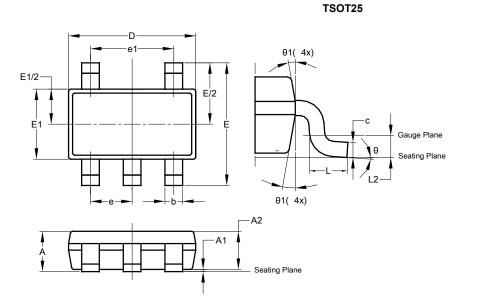
Typical Performance Characteristics (cont.)





Package Outline Dimensions

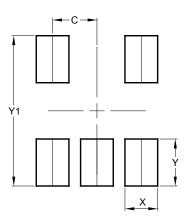
Please see http://www.diodes.com/package-outlines.html for the latest version.



	TSOT25						
Dim	Min	Min Max Ty					
Α		1.00					
A1	0.01	0.10	_				
A2	0.84	0.90	_				
b	0.30	0.45	_				
С	0.12	0.20	-				
D			2.90				
Е			2.80				
E1	_	_	1.60				
е	0.95 BSC						
e1		1.90 BS	С				
L	0.30	0.50	_				
L2	().25 BS	С				
θ	0°	8°	4°				
θ1	4°	12°	_				
All D	Dimens	ions in	mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



TSOT25

Dimensions	Value (in mm)
С	0.950
Х	0.700
Y	1.000
Y1	3.199



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